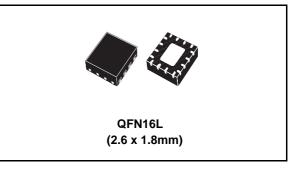


Low voltage high bandwidth Quad SPDT switch

Features

- Ultra low power dissipation:
 - $I_{CC} = 0.2 \mu A \text{ (Max.) at } T_A = 85 ^{\circ} C$
- Low "ON" resistance:
 - $R_{ON} = 4\Omega (T_A = 25^{\circ}C) \text{ at } V_{CC} = 3.0V$
- Wide operating voltage range:
 - V_{CC} (Opr) = 1.65V to 4.3V single supply
- 4.3V tolerant and 1.8V compatible threshold on digital control input at V_{CC} = 2.3V to 3.0V
- Typical bandwidth (-3dB) at 800MHz on all channels
- Latch-up performance exceeds 100mA per JESD 78, Class II
- ESD performance exceeds JESD22
 - 2000-V Human body model (A114-A)
- USB (2.0) high speed (480Mbps) signal switching compliant



Description

The STG3693 is a high-speed CMOS low voltage quad analog SPDT (Single Pole Dual Throw) switch or 2:1 Multiplexer /Demultiplexer Switch fabricated in silicon gate C2MOS technology. It is designed to operate from 1.65V to 4.3V, making this device ideal for portable applications.

The nSEL inputs are provided to control the switch. The switch S1 is ON (they are connected to common Ports Dn) when the nSEL input is held high and OFF (high impedance state exists between the two ports) when SEL is held low; the switch S2 is ON (it is connected to common Port D) when the nSEL input is held low and OFF (high impedance state exists between the two ports) when nSEL is held high.

Additional key features are fast switching speed, break-before-make delay time and ultra low power consumption. All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Table 1. Device summary

Order code	Package	Packaging
STG3693QTR	QFN16L (2.6mm x 1.8mm)	Tape and reel

Contents STG3693

Contents

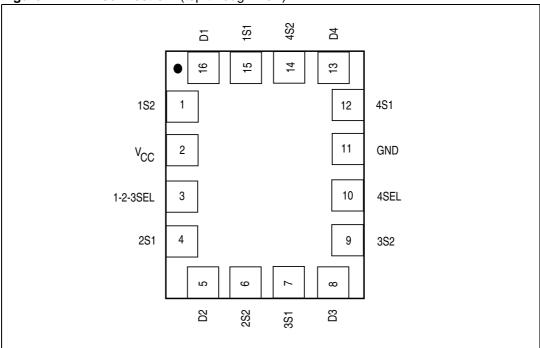
1	Pin settings	3
	1.1 Pin connection	
	1.2 Pin description	3
2	Device summary	4
3	Maximum rating	5
	3.1 Recommended operating conditions	5
4	Electrical characteristics	6
5	Test circuits	9
6	Package mechanical data 1	2
7	Revision history	6

STG3693 Pin settings

1 Pin settings

1.1 Pin connection

Figure 1. Pin connection (top through view)



1.2 Pin description

Table 2. Pin description

Pin N°	Symbol	Name and function
15,1,	1S1, 1S2,	
4,6,	2S1, 2S2,	Independent channels
7,9,	3S1, 3S2,	Independent channels
12,14	4S1, 4S2	
16,5,8,13	D1, D2, D3, D4	Common channels
3, 10	1-2-3SEL, 4SEL	Control
2	V _{CC}	Positive supply voltage
11	GND	Ground (0V)

Note: Exposed pad must be soldered to a floating plane. Do NOT connect to power or ground.

Device summary STG3693

2 Device summary

Figure 2. Input equivalent circuit

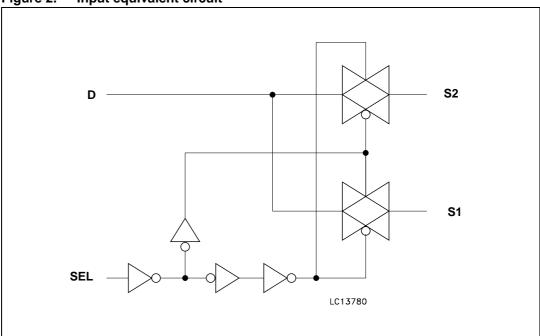


Table 3. Truth table

1-2-3SEL	4SEL	SWITCH 1	SWITCH 2	SWITCH 3	SWITCH 4
Н	Χ	D1-1S1	D2-2S1	D3-3S1	Х
L	Х	D1-1S2	D2-2S2	D3-3S2	Х
Х	Н	Х	Х	Х	4D-4S1
Х	L	Х	Х	Х	4D-4S2

STG3693 Maximum rating

3 Maximum rating

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to 5.5	V
VI	DC input voltage	-0.5 to V _{CC} + 0.5	V
V _{IC}	DC control input voltage	-0.5 to 5.5	V
V _O	DC output voltage	-0.5 to V _{CC} + 0.5	V
I _{IKC}	DC input diode current on control pin (V _{SEL} <0V)	-50	mA
I _{IK}	DC input diode current (V _{SEL} <0V)	±50	mA
I _{OK}	DC output diode current	±20	mA
I _O	DC output current	±128	mA
I _{OP}	DC output current peak (pulse at 1ms, 10% duty cycle)	±300	mA
I _{CC} or I _{GND}	DC V _{CC} or ground current	±100	mA
P _D	Power dissipation at T _A = 70°C ⁽¹⁾	1120	mW
T _{stg}	Storage temperature	-65 to 150	°C
T _L	Lead temperature (10 sec)	300	°C

^{1.} Derate above 70°C by 18.5mW/C

3.1 Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Paramete	r	Value	Unit	
V _{CC}	Supply voltage		1.65 to 4.3	V	
V _I	Input voltage	0 to V _{CC}	V		
V _{IC}	Control input voltage	0 to 4.3	V		
Vo	Output voltage		0 to V _{CC}	V	
T _{op}	Operating temperature		-55 to 125	°C	
dt/dv	Input rise and fall time control	$V_{CC} = 1.65V \text{ to } 2.7V$	0 to 20	ns/V	
ai/av	input	$V_{CC} = 3.0 \text{ to } 4.3 \text{V}$	0 to 10	115/ V	

Electrical characteristics STG3693

4 Electrical characteristics

Table 6. DC Specifications

		Test conditions				Value			
Symbol	Parameter	V 00		T _A	= 25°C	;	-40 to 8	35°C	Unit
		Vcc (V)		Min	Тур	Max	Min	Max	
		1.65 -1.95		0.65V _{CC}			0.65V _{CC}		
	High level	2.3-2.5		1.2			1.2		
V_{IH}	input	2.7-3.0		1.3			1.3		V
	voltage	3.3-3.6		1.4			1.4		
		4.3		1.6			1.6		
		1.65-1.95				0.25			
	Low level	2.3-2.5				0.25			
V_{IL}	input	2.7-3.0				0.25			V
	voltage	3.3-3.6				0.30			
		4.3				0.40			1
		1.8			12.0	16.0			
	Switch ON	2.7	$V_S = 0V$ to		6.3	8.0			
R_{PEAK}	peak resistance	3.0	V _{CC}		5.8	7.5			Ω
		3.7	$I_S = 8mA$		5.0	6.5			
		4.3			4.6	6.0			
Б	Switch On	3.0	$V_S = 3V I_S = 8mA$		4.0	5.2			0
R _{ON}	resistance	3.0	$V_S = 0.8V I_S = 8mA$		5.0	6.5			Ω
		1.8							
	ON resistance	2.7	V _S @ R _{ON}						
ΔR_{ON}	match	3.0	Max		0.3				Ω
	between channels	3.7	$I_S = 8mA$						
		4.3							
		1.8			6.6				
	ON	2.7	$V_S = 0V$ to		2.0				Ω
R_{FLAT}	resistance	3.0	$V_S = 0V \text{ to}$ V_{CC} $I_S = 8\text{mA}$		1.7				
	flatness	3.7			1.5				
	_	4.3			1.6				

Table 6. DC Specifications (continued)

		Test conditions		Value					
Symbol	Parameter	Vec (V)		T _A = 25°C			-40 to 8	Unit	
		Vcc (V)		Min	Тур	Max	Min	Max	
I _{OFF}	OFF state leakage current (SN), (D)	4.3	V _S = 0.3 or 4V			±20		±100	nA
I _{IN}	Input leakage current	0 to 4.3	V _{SEL} = 0 to 4.3V			±0.1		±1	μΑ
I _{CC}	Quiescent supply current	1.65 to 4.3	V _{SEL} = V _{CC} or GND			±0.1		±1.0	μΑ
	Quiescent		V _{1-2-3SEL} , V _{4-SEL} = 1.65V		±37	±50		±100	
I _{CCLV}	supply current low voltage driving	low 4.3	V _{1-2-3SEL} , V _{4-SEL} = 1.80V		±33	±40		±50	μΑ
				V _{1-2-3SEL} , V _{4-SEL} = 2.60V		±11	±20		±30

Table 7. AC electrical characteristics ($C_L = 35pF$, $R_L = 50\Omega$ $t_r = t_f \le ns$)

		Test conditions		Value					
Symbol	Parameter	V (\(\)		-	T _A = 25°C			85°C	Unit
		Vcc (V)		Min	Тур	Max	Min	Max	
t _{PLH} , Propaga t _{PHL} n delay		1.65-1.95			0.30				
	Propagatio	2.3-2.7			0.30				no
	n delay	3.0-3.3			0.25				ns
		3.6-4.3			0.25				
		1.65-1.95	V _S = 0.8V		31				
	TURN-ON	2.3-2.7			20	26		34	ns
t _{ON}	time	3.0-3.3	$V_{S} = 1.5V$		20	20		26	115
		3.6-4.3			20	15		20	
		1.65-1.95	$V_{S} = 0.8$		5				
	TURN- OFF time	2.3-2.7			4	6		8	200
t _{OFF}		3.0-3.3	$V_{S} = 1.5V$		4	6		8	ns
		3.6-4.3			3	5		6	

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Electrical characteristics STG3693

Table 7. AC electrical characteristics ($C_L = 35pF$, $R_L = 50\Omega$, $t_r = t_f \le ns$)

Symbol		Test conditions							
	Parameter	Vcc (V)		-	T _A = 25°C			-40 to 85°C	
				Min	Тур	Max	Min	Max	
Break- before-	1.65-1.95		1	7					
		2.3-2.7	$C_L = 35pF$ $R_L = 50\Omega$	1	5				200
t _D	make time delay	3.0-3.3	$V_{S} = 1.5V$	1	4				ns
	uelay	3.6-4.3		1	3				
		1.65			2.8				
Q	Charge	2.3	$C_L = 100 pF$ $V_{GEN} = 0V$ $R_{GEN} = 0\Omega$		3.5				pC
α	injection	3.0			3.8				
		4.3	02.1		5.0				

Table 8. Analog switch characteristics ($C_L = 5pF$, $R_L = 50\Omega$, $T_A = 25$ °C)

		Te	est Conditions			Value	!					
Symbol	Parameter	Vcc (V)		T,	_A = 25°	°C	-40 to 85°C		Unit			
		VCC (V)		Min	Тур	Max	Min	Max				
OIRR Off Isolation	Off location (1)	1.65 -	$V_S = 1V_{RMS}, f = 1MHz$ Signal = 0 dBm		-79				J.			
	On isolation (*)	4.3	$V_S = 1V_{RMS}, f = 10MHz$ Signal = 0 dBm		-60				dB			
	Crosstalk	Createlli	Croastally	Crosstalk	1.65 -	$V_S = 1V_{RMS}, f = 1MHz$ Signal = 0 dBm		-78				dB
Xtalk		4.3	$V_S = 1V_{RMS}, f = 10MHz$ Signal = 0 dBm		-61				ИΒ			
THD	Total harmonic distortion	3.7	$f = 20 \text{Hz to } 20 \text{kHz}$ $R_L = 32 \Omega C_L = 50 \Omega$ $V_{\text{IN}} = 2.8 V_{\text{P-P}}$ $V_{\text{DC}} = V_{\text{CC}} / 2$		0.01	0.02			%			
PSRR	Power supply rejection ratio	3.7	$f = 217Hz,$ $R_L = 32\Omega C_L = 50\Omega$ $V_{ripple} = 150mV$ $V_{DC} = V_{CC}/2$		-60				dB			
BW	-3dB Bandwidth	3.0 - 4.3	$R_L = 50\Omega$ Signal = 0dBm		800				MHz			
D_G	Differential gain	3.0 - 4.3	$RL = 150\Omega$		0.64				%			

	71114109 01111		actoriotice (of ob	· , · \L	0015	· A -	,		
Symbol		Te	Test Conditions		Value				
	Parameter	.,		Т	T _A = 25°C			-40 to 85°C	
		Vcc (V)		Min	Тур	Max	Min	Max	
D _P	Differential phase	3.0 - 4.3	RL = 150Ω		0.1				deg
C _{IN}	Control pin input capacitance		V _{CC} = 0V		6.2				
C _{ON}	Sn Port capacitance when switch is enabled	3.3	f = 1MHz		10				pF
C _{OFF}	Sn port capacitance when switch is disabled	3.3	f = 1MHz		5				

Table 8. Analog switch characteristics ($C_L = 5pF$, $R_L = 50\Omega$, $T_A = 25$ °C)

Table 9. USB related AC electrical characteristics

Symb ol	Parameter	Test conditions		Value					
		V _{CC} (V)		T,	T _A = 25°C		-40 to 85°C		Unit
				Min	Тур	Max	Min	Max	
t _{SK(0)}	Channel-to-channel skew	3.0 to 3.6	C _L =10pF		26				ps
t _{SK(P)}	Skew of opposite transition of the same output	3.0 to 3.6	C _L =10pF		60				ps
TJ	Total jitter	3.0 to 3.6	$R_L = 50\Omega$ $C_L = 10pF$, $t_R = t_F =$ 750ps at 480Mbps		130				ps

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^{1.} Off Isolation = 20Log10 (V_D/V_S), V_D = output. V_S = input to off switch.

Test circuits STG3693

5 Test circuits

Figure 3. ON-Resistance

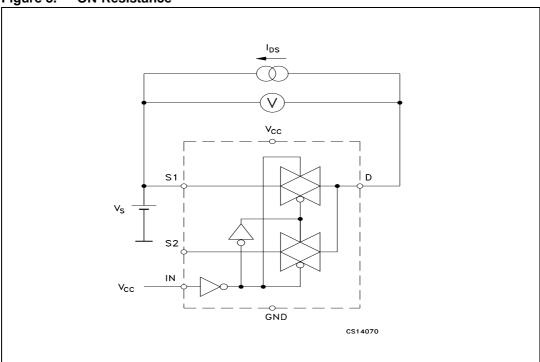
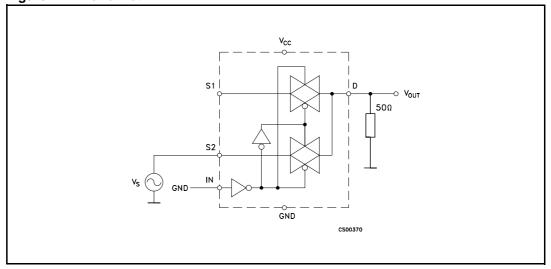


Figure 4. Bandwidth



STG3693 Test circuits

Figure 5. OFF Leakage

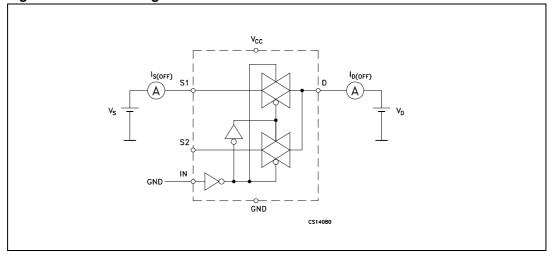


Figure 6. Channel to channel crosstalk

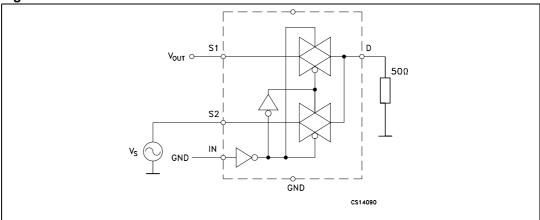
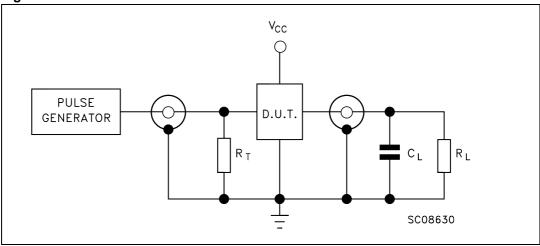


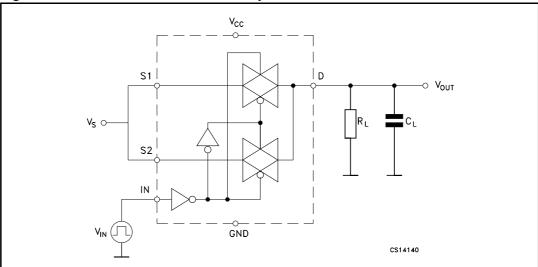
Figure 7. Test circuit



- 1. $C_L = 5/35pF$ or equivalent: (includes jig capacitance)
- 1. $R_L = 50\Omega$ or equivalent
- 1. $R_T = Z_{OUT}$ of pulse generator (typically 50Ω

Test circuits STG3693

Figure 8. Break-before-make time delay



Break-before-make time delay Figure 9.

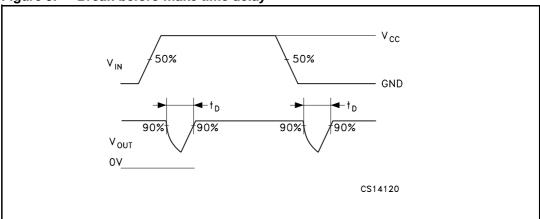
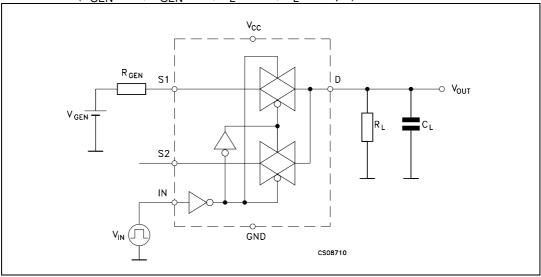


Figure 10. Switching time and charge injection $(V_{GEN}=0V,~R_{GEN}=0\Omega,~R_L=1M\Omega,~C_L=100pF)$



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STG3693 Test circuits

Figure 11. Switching time and charge injection $(V_{GEN}=0V,~R_{GEN}=0\Omega,~R_L=1M\Omega,~C_L=100pF)$

Figure 12. Turn ON, turn OFF delay time

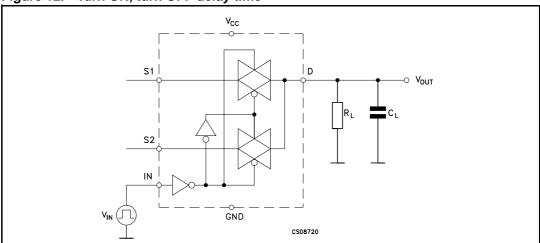
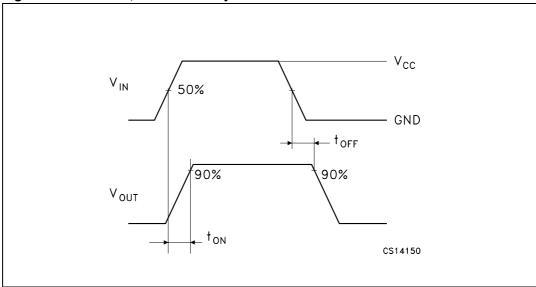


Figure 13. Turn ON, turn OFF delay time



Package mechanical data 6

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

BOTTOM VIEW PIN 1 ID 16 15 16x (4 LEADS x SIDE) 11 0.1 C A3 SEATING PLANE C ___O.08 C LEADS COPLANARITY 12 11 10 13 8 14 15 6 16 5 PIN 1 ID 2 D/2 -TOP VIEW

Figure 14. QFN16L (2.6x1.8mm) package outline

1.90

0.80

0.35

Symbol	millimeters					
Symbol	Min	Тур	Max			
А	0.45	0.50	0.55			
A1	0	0.02	0.05			
A3		0.127				
b	0.15	0.20	0.25			
D	2.50	2.60	2.70			
D2	1.40	1.50	1.60			

1.80

0.70

0.40

0.30

Table 10. QFN16L (2.6x1.8mm) mechanical data⁽¹⁾

1.70

0.60

0.25

The leads size is comprehensive of the thickness of the leads finishing material.

Dimensions do not include mold protusion.

Ε

E2

е

L

Package outline exclusive of metal burrs dimensions.

Shipping media tape and reel units: 3000

Figure 15. Foot print recommendation

^{1.} VFQFPN - Standard for thermally enhanced vey fine pitch quad flat package no leads.

KO ±0.10 | |±0.05 0.30 *A0* 2.10 ±0.05 *A0* ±0.1 ±0.05 BO 2.90 ± 0.05 COVER * ±0.10 KO 0.75 ±0.05 - 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0,20 13,40 +0.70 0 ±0.5 Detail of Pin Hole

Figure 16. QFN16L (2.6mmx1.8mm) tape & reel information

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(Scale:2/1)

STG3693 Revision history

7 Revision history

Table 11. Revision history

Date	Revision	Changes	
3-Jan-2006	1	First release	
23-Jul-2007	2	Updated C _{OFF} value in <i>Table 8 on page 8</i>	

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